MOSFET - Power, Single N-Channel, PQFN8

100 V, 10.8 mΩ, 83 A

Product Preview

NTMFS010N10G

Features

- Wide SOA for Linear Mode Operation
- Low $R_{DS(on)}$ to Minimize Conduction Loss
- High Peak UIS Current Capability for Ruggedness
- Small Footprint (5x6 mm) for Compact Design
- These Devices are Pb−Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- 48 V Hot Swap System, Load Switch, Soft Start, E−Fuse

MAXIMUM RATINGS (T_J = 25°C, Unless otherwise specified)

Parameter			Symbol	Value	Unit
Drain−to−Source Breakdown Voltage			$V_{(BR)DSS}$	100	V
Gate−to−Source Voltage			V_{GS}	±20	V
Continuous Drain Current $R_{\theta JC}$ (Note 2)	Steady State	T_C = 25°C	I_D	83	A
		T_C = 100°C	I_D	58	A
Power Dissipation $R_{\theta JC}$ (Note 2)		T_C = 25°C	P_D	150	W
		T_C = 100°C	P_D	75	W
Continuous Drain Current $R_{\theta JA}$ (Note 1, 2)	Steady State	T_C = 25°C	I_D	11	A
		T_C = 100°C	I_D	8	A
Power Dissipation $R_{\theta JA}$ (Note 1, 2)		T_C = 25°C	P_D	3	W
		T_C = 100°C	P_D	1.5	W
Pulsed Drain Current	T_A = 25°C, t_p = 10 μs		I_{DM}	1247	A
Operating Junction and Storage Temperature Range			T_J, T_{stg}	−55 to +175	°C
Source Current (Body Diode)			I_S	125	A
Single Pulse Drain−to−Source Avalanche Energy (I_{AV} = 38.8 A, L = 0.3 mH)			E_{AS}	226	mJ
Lead Temperature Soldering Reflow for Soldering Purposes (1/8" from case for 10 s)			T_L	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Surface−mounted on FR4 board using 1 in^2 pad size, 1 oz Cu pad.
2. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.

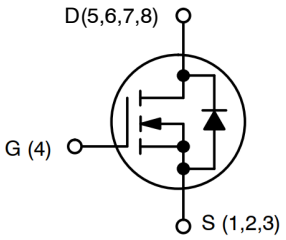
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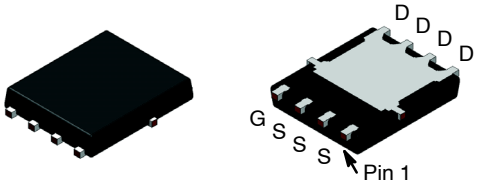
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$V_{(BR)DSS}$	$R_{DS(ON)}$ MAX	I_D MAX
100 V	10.8 mΩ @ 10 V	83 A

N−Channel MOSFET

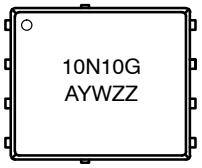




Top Bottom

PQFN8 5x6
(Power 56)
CASE 483AE

MARKING DIAGRAM



A = Assembly Location
Y = Year
W = Work Week
ZZ = Lot Traceability

ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

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THERMAL CHARACTERISTICS

Symbol	Parameter	Max	Unit
$R_{\theta JC}$	Junction−to−Case − Steady State	1.0	°C/W
$R_{\theta JA}$	Junction−to−Ambient − Steady State	50	

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise noted)

Symbol	Parameter	Test Conditions		Min	Typ	Max	Unit
OFF CHARACTERISTICS							
$V_{(BR)DSS}$	Drain−to−Source Breakdown Voltage	V_{GS} = 0 V, I_D = 250 μA		100			V
$V_{(BR)DSS}$ / T_J	Drain−to−Source Breakdown Voltage Temperature Coefficient	I_D = 250 μA, ref to 25°C			87.9		mV/°C
I_{DSS}	Zero Gate Voltage Drain Current	V_{GS} = 0 V, V_{DS} = 80 V	T_J = 25°C			1	μA
			T_J = 125°C			100	
I_{GSS}	Gate−to−Source Leakage Current	V_{DS} = 0 V, V_{GS} = ±20 V				±100	nA
ON CHARACTERISTICS (Note 3)							
$V_{GS(TH)}$	Gate Threshold Voltage	V_{GS} = V_{DS}, I_D = 164 μA		2.0	3.0	4.0	V
$V_{GS(TH)}$ / T_J	Negative Threshold Temperature Coefficient	I_D = 164 μA, ref to 25°C			−9.2		mV/°C
$R_{DS(on)}$	Drain−to−Source On Resistance	V_{GS} = 10 V, I_D = 31 A			8.6	10.8	mΩ
g_{FS}	Forward Transconductance	V_{DS} = 5 V, I_D = 31 A			21		S
R_G	Gate−Resistance	V_{GS} = 0 V, f = MHz			0.52		Ω
CHARGES & CAPACITANCES							
C_{ISS}	Input Capacitance	V_{GS} = 0 V, f = 1 MHz, V_{DS} = 50 V			3950		pF
C_{OSS}	Output Capacitance				430		
C_{RSS}	Reverse Transfer Capacitance				60		
$Q_{G(TOT)}$	Total Gate Charge	V_{GS} = 10 V, V_{DS} = 50 V, I_D = 31 A			58.5		nC
Q_{GS}	Gate−to−Source Charge				22		
Q_{GD}	Gate−to−Drain Charge				14		
Q_{OSS}	Output Charge	V_{GS} = 0 V, V_{DD} = 50 V			41		
SWITCHING CHARACTERISTICS (Note 3)							
$t_{d(ON)}$	Turn−On Delay Time	V_{GS} = 10 V, V_{DS} = 50 V, I_D = 31 A, R_G = 4.7 Ω			23		ns
t_r	Rise Time				14		
$t_{d(OFF)}$	Turn−Off Delay Time				34		
t_f	Fall Time				9		
DRAIN−SOURCE DIODE CHARACTERISTICS							
V_{SD}	Forward Diode Voltage	V_{GS} = 0 V, I_S = 31 A	T_J = 25°C		0.83	1.2	V
			T_J = 125°C		0.7		
t_{RR}	Reverse Recovery Time	V_{GS} = 0 V, dI_S/dt = 300 A/μs, I_S = 15 A			36		ns
Q_{RR}	Reverse Recovery Charge				147		nC
t_{RR}	Reverse Recovery Time	V_{GS} = 0 V, dI_S/dt = 1000 A/μs, I_S = 15 A			24		ns
Q_{RR}	Reverse Recovery Charge				288		nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS

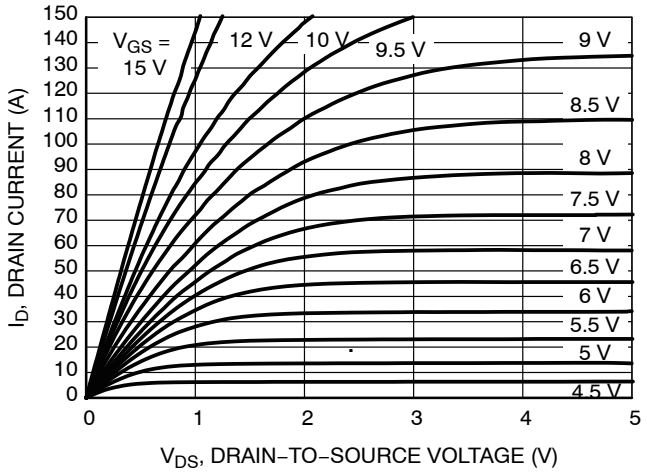


Figure 1. On−Region Characteristics

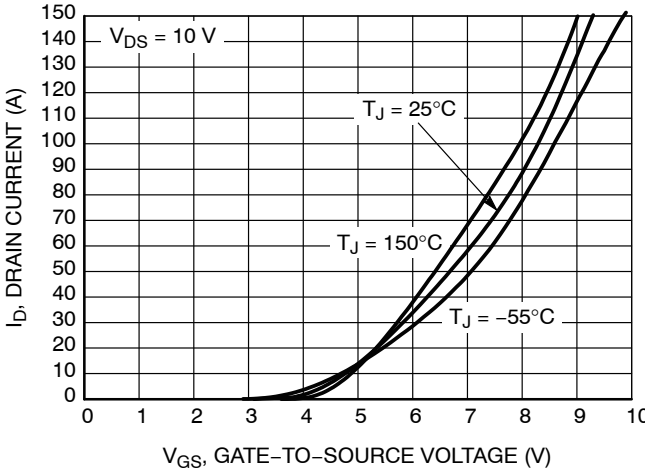


Figure 2. Transfer Characteristics

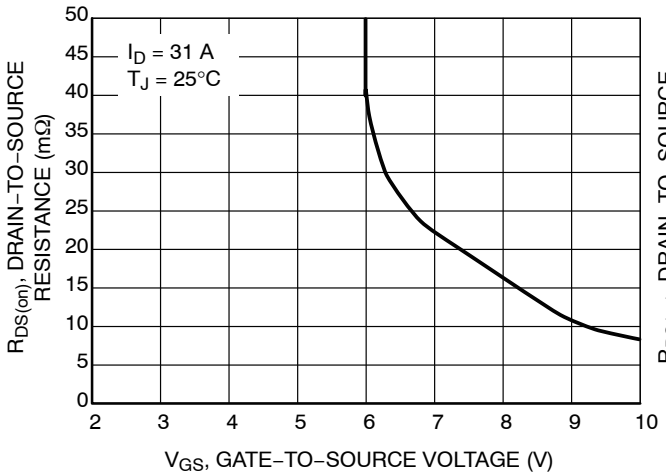


Figure 3. On−Resistance vs. Gate−to−Source Voltage

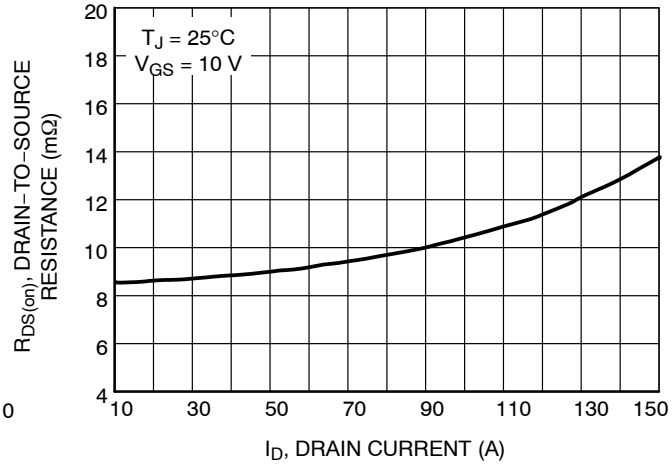


Figure 4. On−Resistance versus Drain Current and Gate Voltage

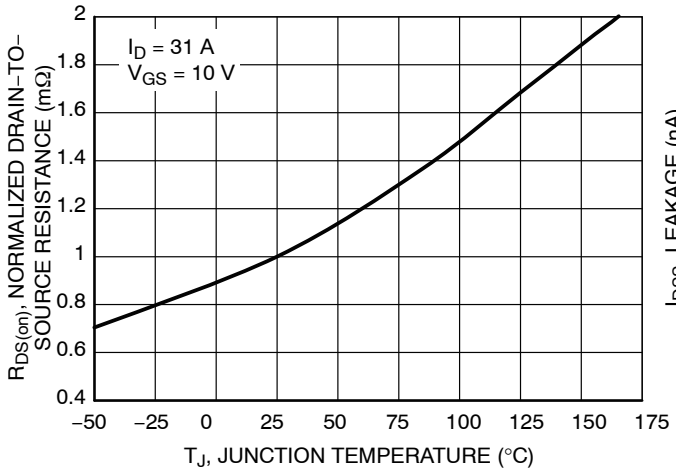


Figure 5. On−Resistance Variation with Temperature

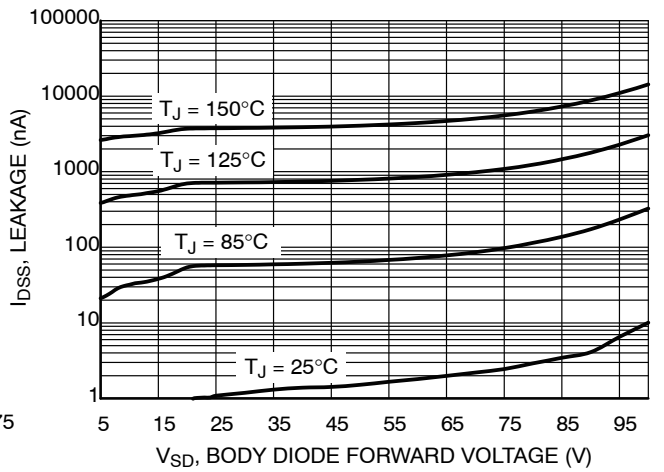


Figure 6. Drain−to−Source Leakage Current versus Voltage

TYPICAL CHARACTERISTICS

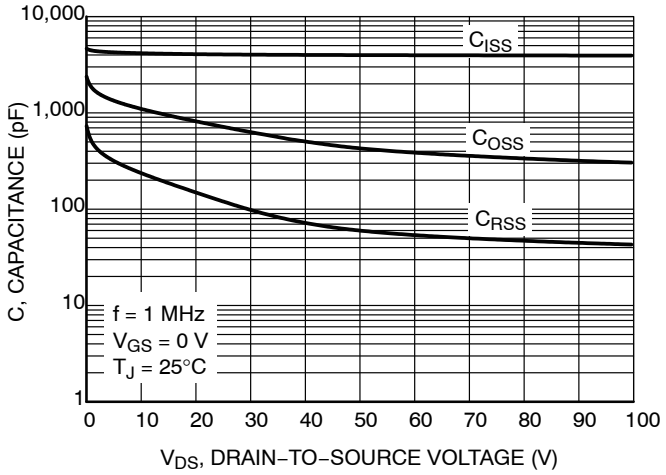


Figure 7. Capacitance Variation

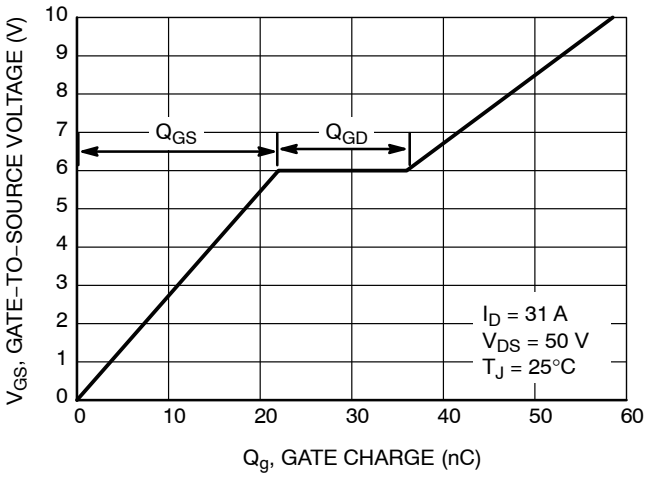


Figure 8. Gate−to−Source vs. Total Charge

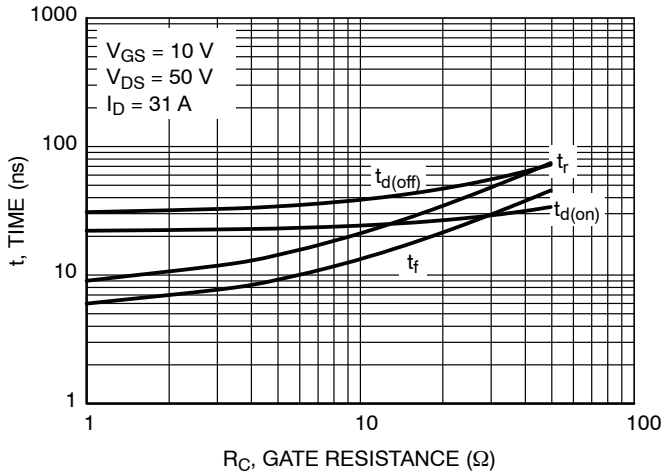


Figure 9. Resistive Switching Time Variation versus Gate Resistance

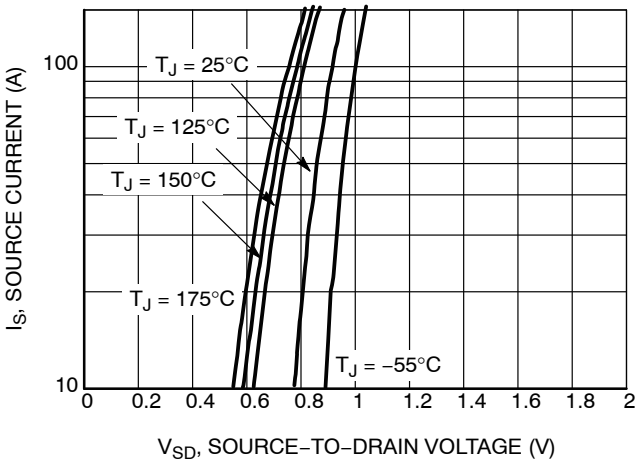


Figure 10. Diode Forward Voltage Versus Current

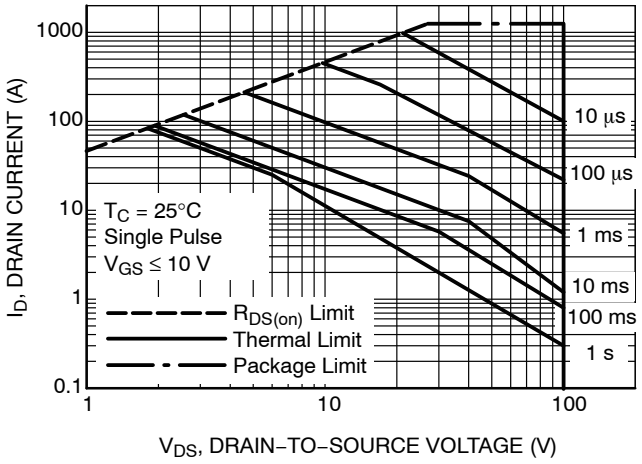


Figure 11. Forward Bias Safe Operating Area

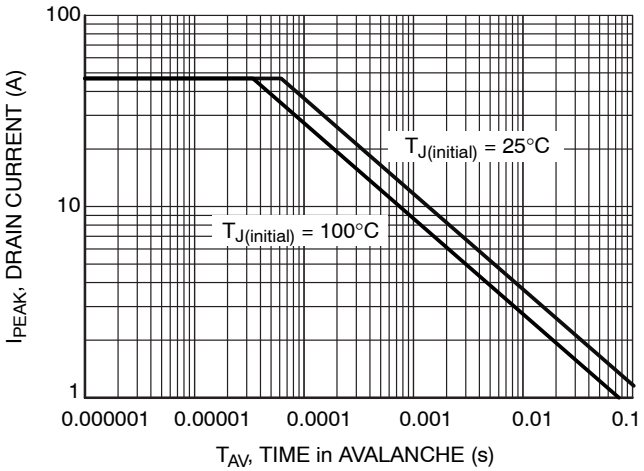


Figure 12. Maximum Drain Current Versus Time in Avalanche

TYPICAL CHARACTERISTICS

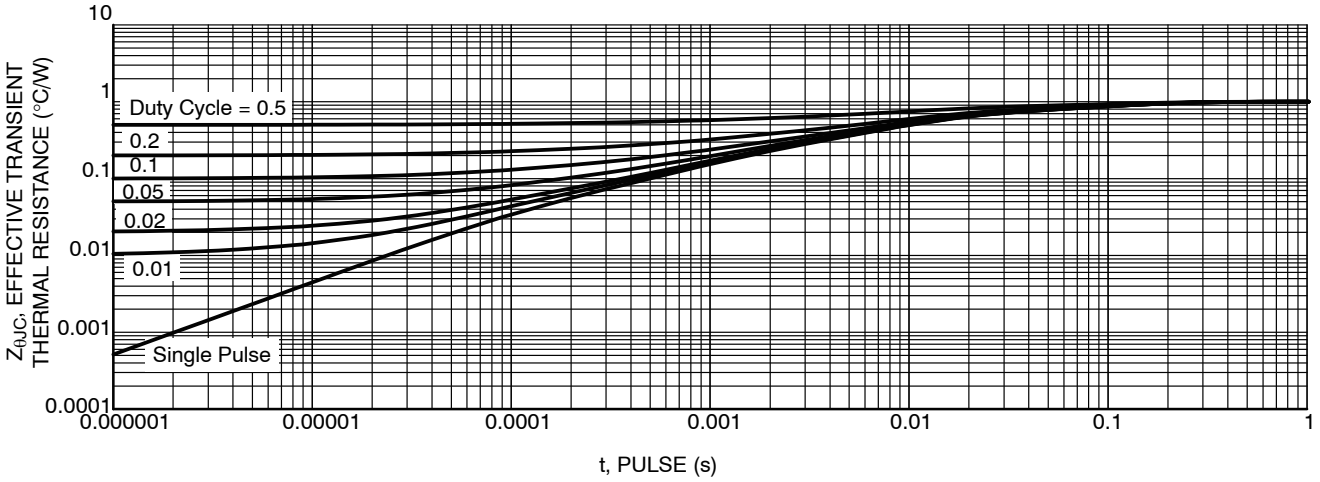


Figure 13. Transient Thermal Impedance

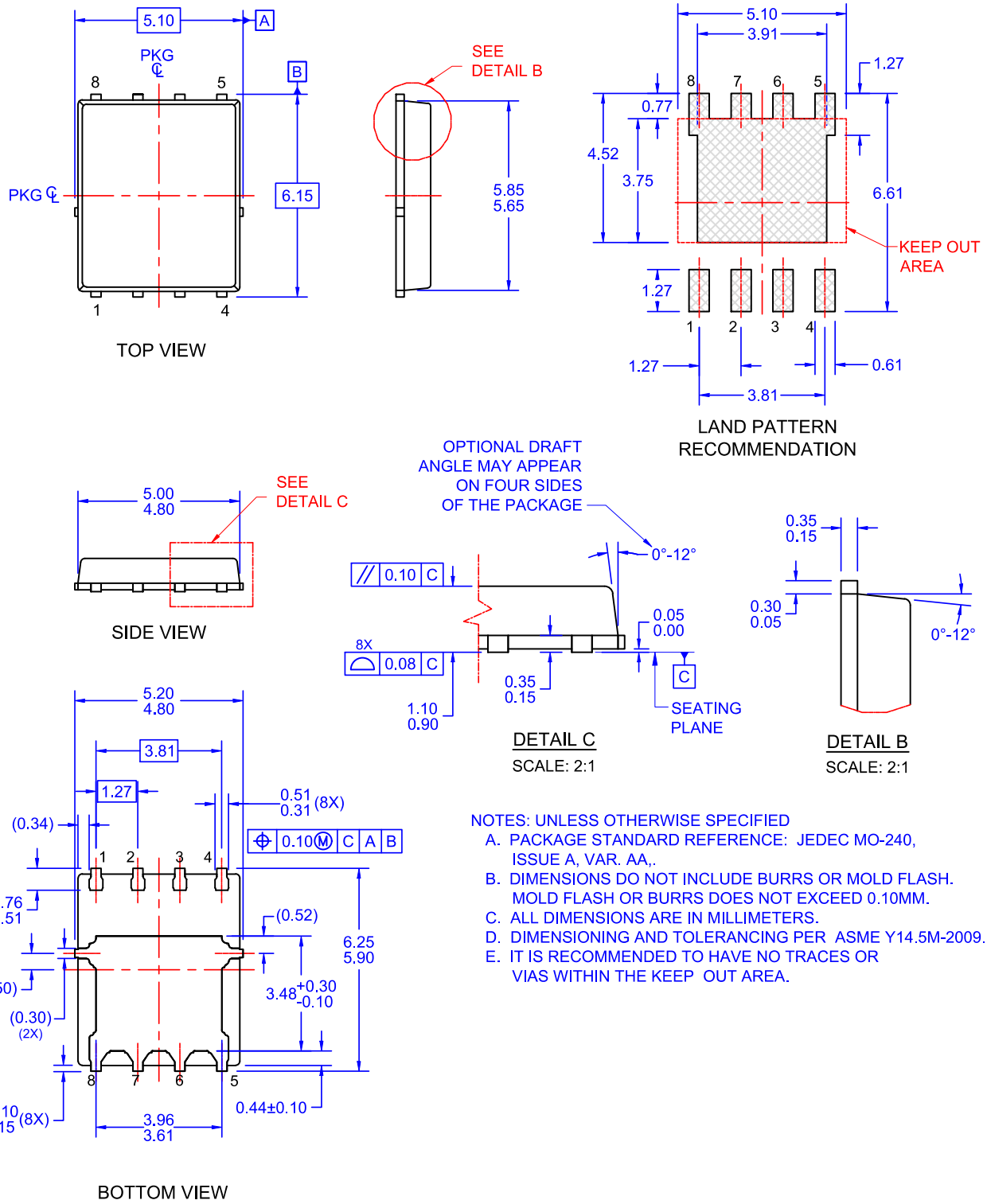
ORDERING INFORMATION

Device	Device Marking	Package	Shipping (Qty / Packing)†
NTMFS010N10GTWG	10N10G	PQFN8 (Pb−Free/Halogen Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

PQFN8 5X6, 1.27P
CASE 483AE
ISSUE A



NOTES: UNLESS OTHERWISE SPECIFIED

A. PACKAGE STANDARD REFERENCE: JEDEC MO-240, ISSUE A, VAR. AA,.
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